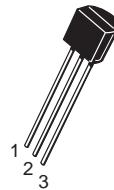
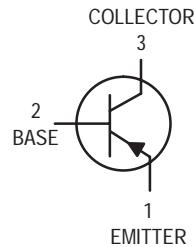


## General Purpose Transistors

PNP Silicon

**2N4402**  
**2N4403\***

\*Motorola Preferred Device



CASE 29-04, STYLE 1  
TO-92 (TO-226AA)

### MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector-Emitter Voltage	$V_{CEO}$	40	Vdc
Collector-Base Voltage	$V_{CBO}$	40	Vdc
Emitter-Base Voltage	$V_{EBO}$	5.0	Vdc
Collector Current — Continuous	$I_C$	600	mAdc
Total Device Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	625 5.0	mW mW/ $^\circ\text{C}$
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_D$	1.5 12	Watt mW/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_J, T_{stg}$	-55 to +150	$^\circ\text{C}$

### THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Ambient	$R_{\theta JA}$	200	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case	$R_{\theta JC}$	83.3	$^\circ\text{C}/\text{W}$

### ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
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### OFF CHARACTERISTICS

Collector-Emitter Breakdown Voltage <sup>(1)</sup> ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $I_B = 0$ )	$V_{(\text{BR})\text{CEO}}$	40	—	Vdc
Collector-Base Breakdown Voltage ( $I_C = 0.1 \text{ mA}_\text{dc}$ , $I_E = 0$ )	$V_{(\text{BR})\text{CBO}}$	40	—	Vdc
Emitter-Base Breakdown Voltage ( $I_E = 0.1 \text{ mA}_\text{dc}$ , $I_C = 0$ )	$V_{(\text{BR})\text{EBO}}$	5.0	—	Vdc
Base Cutoff Current ( $V_{CE} = 35 \text{ Vdc}$ , $V_{EB} = 0.4 \text{ Vdc}$ )	$I_{BEV}$	—	0.1	$\mu\text{A}_\text{dc}$
Collector Cutoff Current ( $V_{CE} = 35 \text{ Vdc}$ , $V_{EB} = 0.4 \text{ Vdc}$ )	$I_{CEX}$	—	0.1	$\mu\text{A}_\text{dc}$

1. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

Preferred devices are Motorola recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$  unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Max	Unit
<b>ON CHARACTERISTICS</b>					
DC Current Gain ( $I_C = 0.1 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ V}_\text{dc}$ )	2N4403	$h_{FE}$	30	—	—
( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ V}_\text{dc}$ )	2N4402 2N4403		30	—	—
( $I_C = 10 \text{ mA}_\text{dc}$ , $V_{CE} = 1.0 \text{ V}_\text{dc}$ )	2N4402 2N4403		50	—	—
( $I_C = 150 \text{ mA}_\text{dc}$ , $V_{CE} = 2.0 \text{ V}_\text{dc}$ ) <sup>(1)</sup>	2N4402 2N4403		50	150	—
( $I_C = 500 \text{ mA}_\text{dc}$ , $V_{CE} = 2.0 \text{ V}_\text{dc}$ ) <sup>(1)</sup>	Both		100	300	—
Collector-Emitter Saturation Voltage <sup>(1)</sup> ( $I_C = 150 \text{ mA}_\text{dc}$ , $I_B = 15 \text{ mA}_\text{dc}$ ) ( $I_C = 500 \text{ mA}_\text{dc}$ , $I_B = 50 \text{ mA}_\text{dc}$ )		$V_{CE(\text{sat})}$	—	0.4 0.75	$\text{V}_\text{dc}$
Base-Emitter Saturation Voltage <sup>(1)</sup> ( $I_C = 150 \text{ mA}_\text{dc}$ , $I_B = 15 \text{ mA}_\text{dc}$ ) ( $I_C = 500 \text{ mA}_\text{dc}$ , $I_B = 50 \text{ mA}_\text{dc}$ )		$V_{BE(\text{sat})}$	0.75 —	0.95 1.3	$\text{V}_\text{dc}$

## SMALL-SIGNAL CHARACTERISTICS

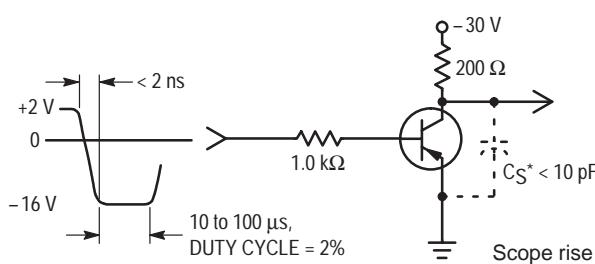
Current-Gain — Bandwidth Product ( $I_C = 20 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ , $f = 100 \text{ MHz}$ )	2N4402 2N4403	$f_T$	150 200	—	MHz
Collector-Base Capacitance ( $V_{CB} = 10 \text{ V}_\text{dc}$ , $I_E = 0$ , $f = 1.0 \text{ MHz}$ )		$C_{cb}$	—	8.5	$\text{pF}$
Emitter-Base Capacitance ( $V_{EB} = 0.5 \text{ V}_\text{dc}$ , $I_C = 0$ , $f = 1.0 \text{ MHz}$ )		$C_{eb}$	—	30	$\text{pF}$
Input Impedance ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )	2N4402 2N4403	$h_{ie}$	750 1.5 k	7.5 k 15 k	ohms
Voltage Feedback Ratio ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )		$h_{re}$	0.1	8.0	$\times 10^{-4}$
Small-Signal Current Gain ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )	2N4402 2N4403	$h_{fe}$	30 60	250 500	—
Output Admittance ( $I_C = 1.0 \text{ mA}_\text{dc}$ , $V_{CE} = 10 \text{ V}_\text{dc}$ , $f = 1.0 \text{ kHz}$ )		$h_{oe}$	1.0	100	$\mu\text{mhos}$

## SWITCHING CHARACTERISTICS

Delay Time	( $V_{CC} = 30 \text{ V}_\text{dc}$ , $V_{BE} = +2.0 \text{ V}_\text{dc}$ ,	$t_d$	—	15	ns
Rise Time	$I_C = 150 \text{ mA}_\text{dc}$ , $I_{B1} = 15 \text{ mA}_\text{dc}$ )	$t_r$	—	20	ns
Storage Time	( $V_{CC} = 30 \text{ V}_\text{dc}$ , $I_C = 150 \text{ mA}_\text{dc}$ ,	$t_s$	—	225	ns
Fall Time	$I_{B1} = 15 \text{ mA}$ , $I_{B2} = 15 \text{ mA}$ )	$t_f$	—	30	ns

1. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

## SWITCHING TIME EQUIVALENT TEST CIRCUIT



\*Total shunt capacitance of test jig connectors, and oscilloscope

Figure 1. Turn-On Time

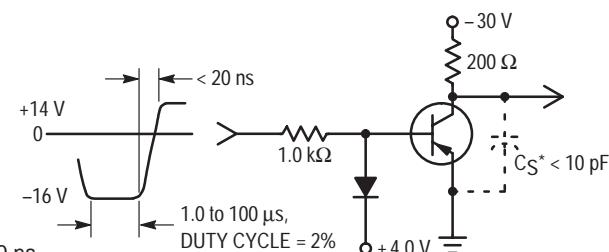


Figure 2. Turn-Off Time

## TRANSIENT CHARACTERISTICS

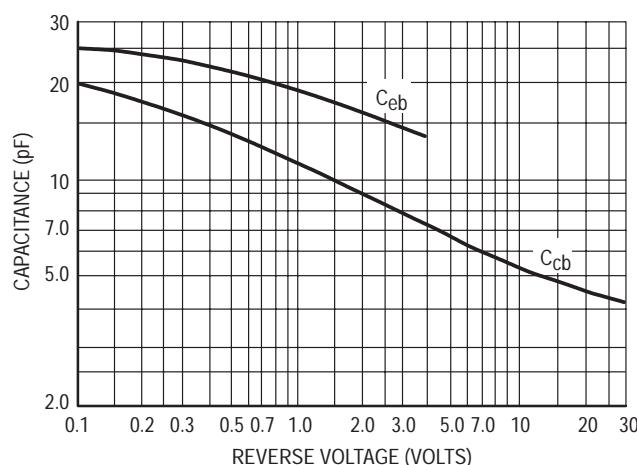


Figure 3. Capacitances

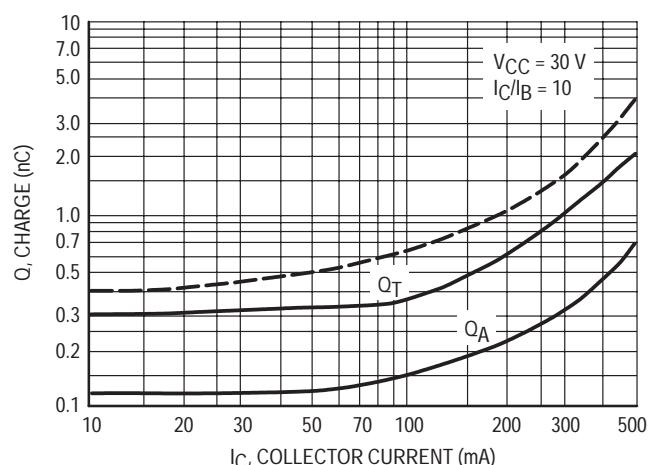


Figure 4. Charge Data

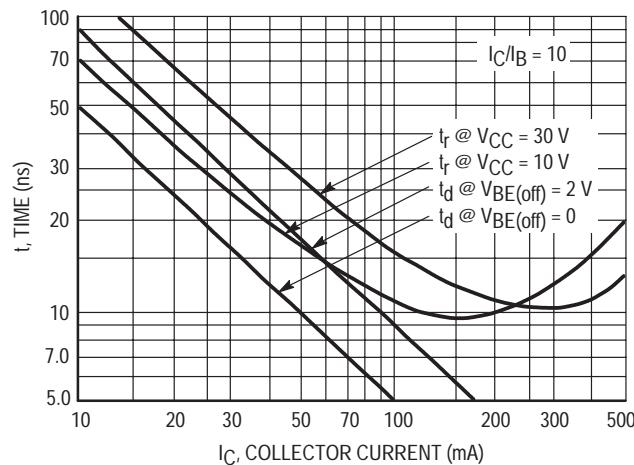


Figure 5. Turn-On Time

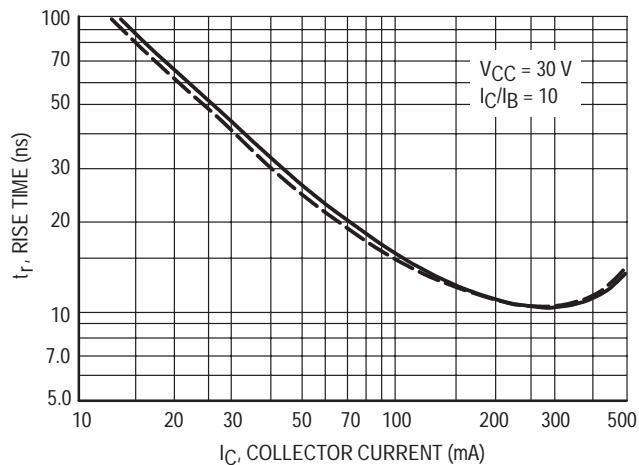


Figure 6. Rise Time

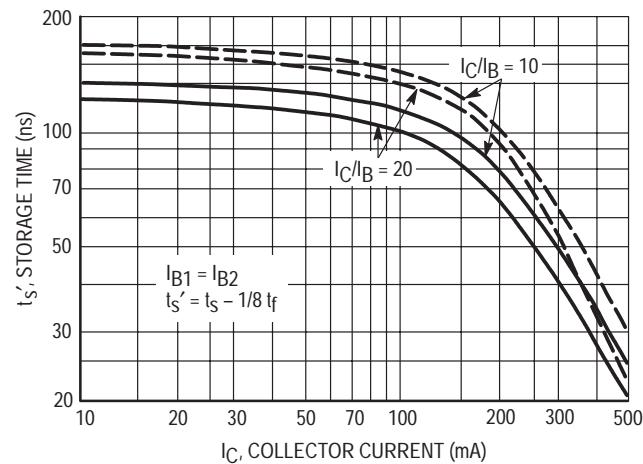
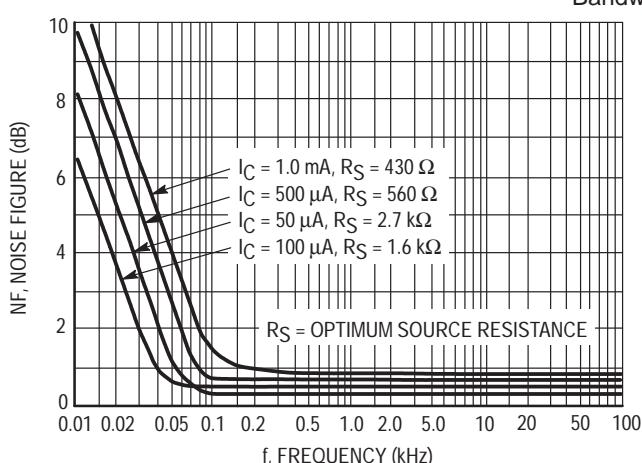


Figure 7. Storage Time

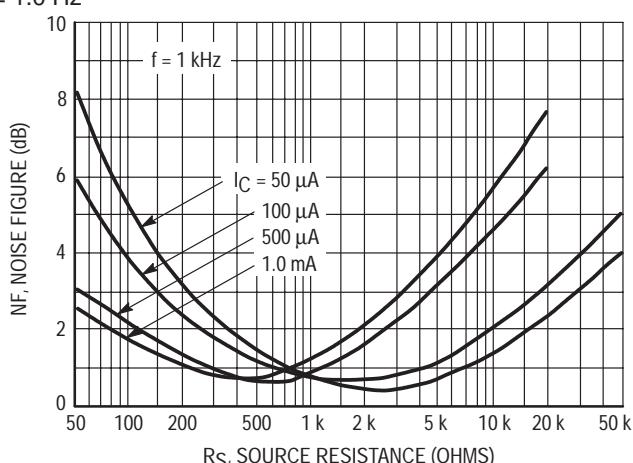
### SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE

$V_{CE} = -10$  Vdc,  $T_A = 25^\circ\text{C}$

Bandwidth = 1.0 Hz



**Figure 8. Frequency Effects**

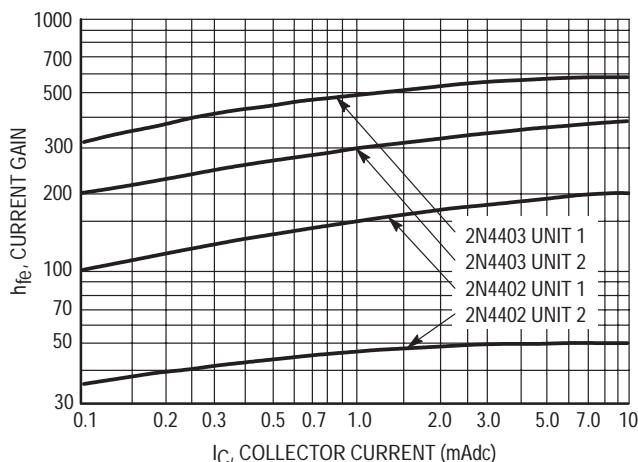


**Figure 9. Source Resistance Effects**

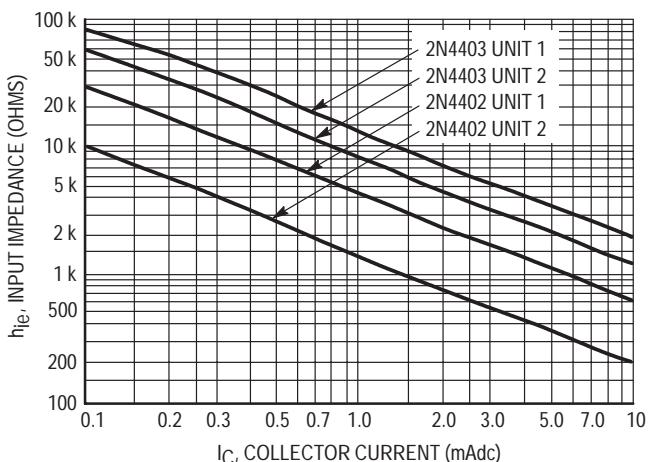
### **h** PARAMETERS

$V_{CE} = -10$  Vdc,  $f = 1.0$  kHz,  $T_A = 25^\circ\text{C}$

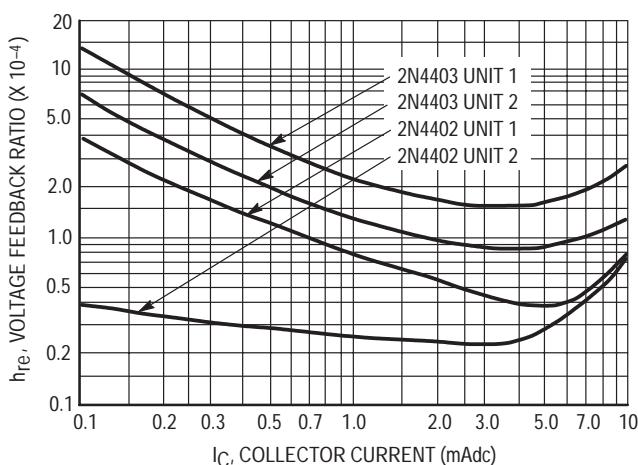
This group of graphs illustrates the relationship between  $h_{fe}$  and other "h" parameters for this series of transistors. To obtain these curves, a high-gain and a low-gain unit were selected from both the 2N4402 and 2N4403 lines, and the same units were used to develop the correspondingly-numbered curves on each graph.



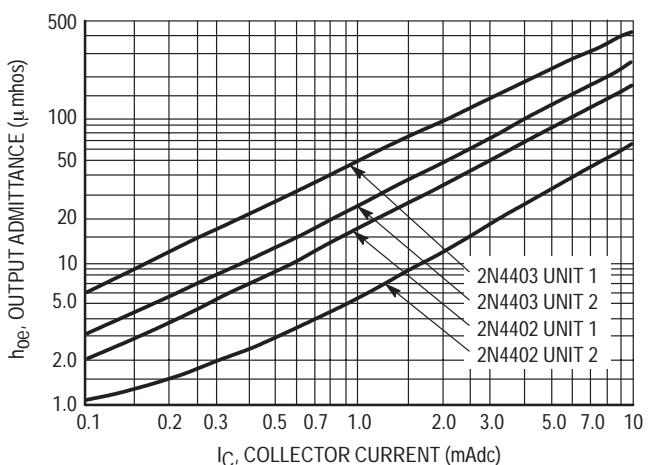
**Figure 10. Current Gain**



**Figure 11. Input Impedance**



**Figure 12. Voltage Feedback Ratio**



**Figure 13. Output Admittance**

## STATIC CHARACTERISTICS

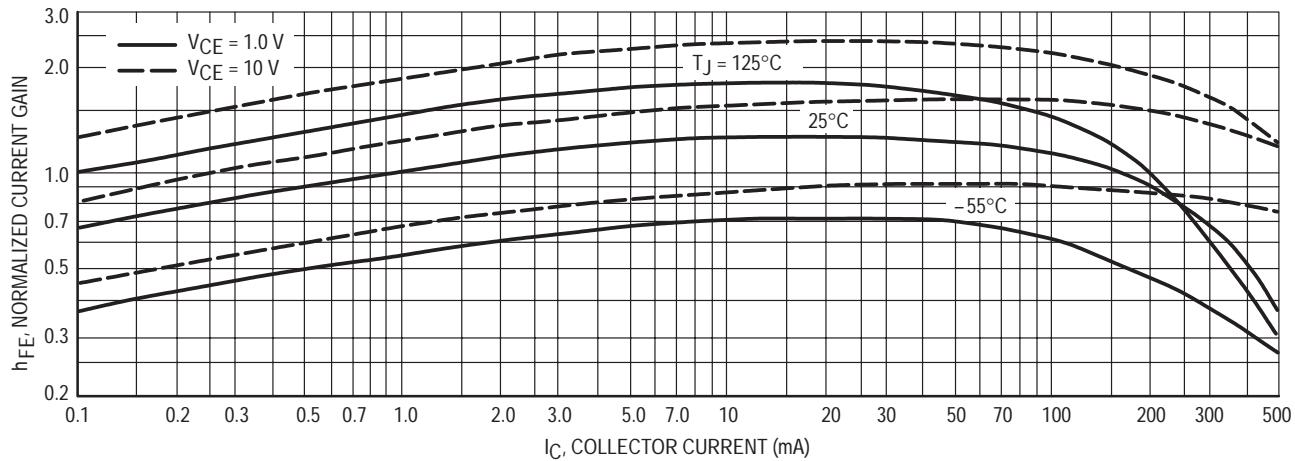


Figure 14. DC Current Gain

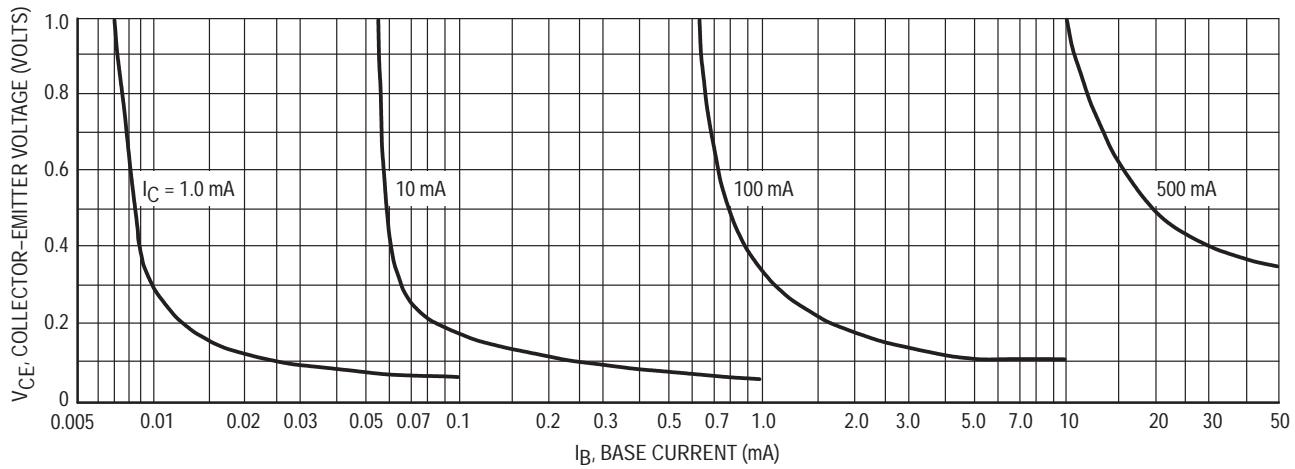


Figure 15. Collector Saturation Region

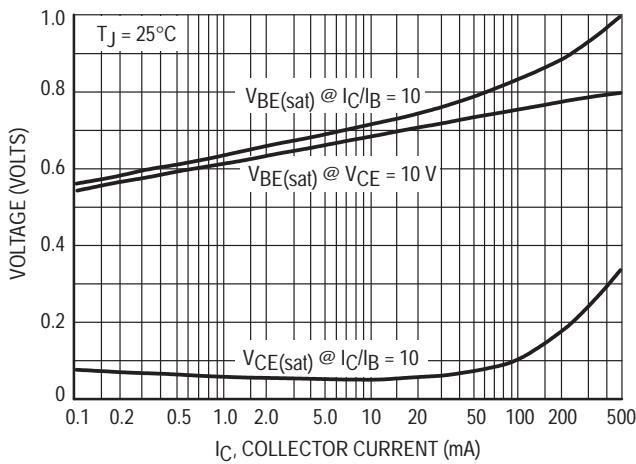


Figure 16. "On" Voltages

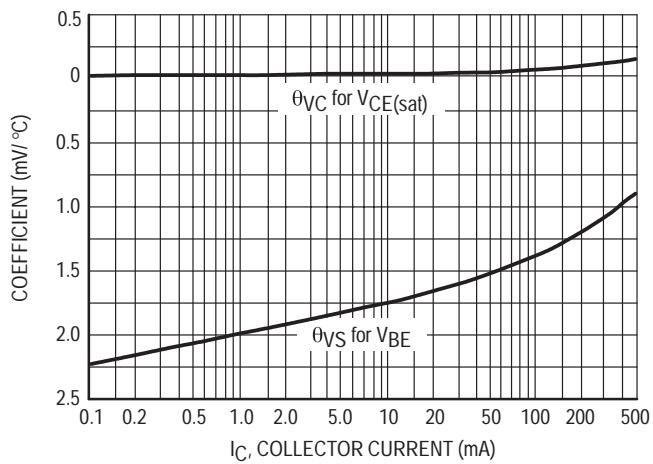


Figure 17. Temperature Coefficients